

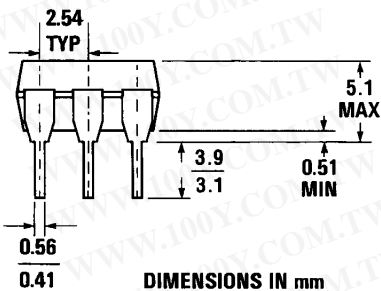
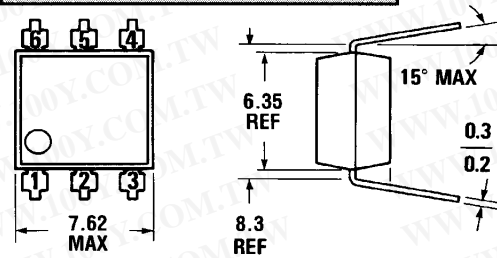
勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
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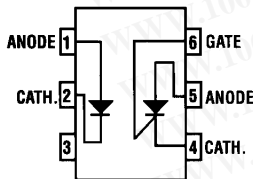
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4N39 4N40

PACKAGE DIMENSIONS



ST1603



ST1602

Equivalent Circuit

DESCRIPTION

The 4N39 and 4N40 have a gallium-arsenide infrared emitting diode optically coupled with a light activated silicon controlled rectifier in a dual in-line package.

FEATURES & APPLICATIONS

- High efficiency, low degradation, liquid epitaxial LED
- 10 A, T²L compatible, solid state relay
- 25 W logic indicator lamp driver
- 400 V symmetrical transistor coupler
- Underwriters Laboratory (UL) recognized — File #E90700

ABSOLUTE MAXIMUM RATINGS

TOTAL PACKAGE

- *Storage temperature -55°C to 150°C
- *Operating temperature -55°C to 100°C
- *Lead solder temperature 260°C for 10 sec
- *Total power dissipation (-55°C to 50°C) .. 450 mW
- Derate linearly (above 50°C) 9.0 mW/°C

INPUT DIODE

- *Power dissipation (-55°C to 50°C) 100 mW
- Derate linearly (above 50°C) 2 mW/°C
- *Continuous forward current (-55°C to 50°C) 60 mA
- *Peak forward current (-55°C to 50°C) 1 A
- *Reverse voltage (-55°C to 50°C) 6 V

DETECTOR

- *Power dissipation (-55°C to 50°C) 400 mW
- Derate linearly (above 50°C) 8 mW/°C
- *Off-state and reverse voltage 4N39 200 V
- *(-55°C to +100°C) 4N40 400 V
- *Peak reverse gate voltage(-55°C to 50°C) 6 V
- *Direct on-state current (-55°C to 50°C) 300 mA
- *Surge on-state current (-55°C to 50°C) (100μS) 10 A
- *Peak gate current (-55°C to 50°C) 10 mA

*Indicates JEDEC Registered Data

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ$ Unless Otherwise Specified)

INDIVIDUAL COMPONENT CHARACTERISTICS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
*Forward voltage	V_F		1.1	1.5	V	$I_F = 10 \text{ mA}$
*Reverse leakage current	I_R			10	μA	$V_R = 3 \text{ V}$
Capacitance	C_J		50		pF	$V = 0 \text{ V}, f = 1 \text{ MHz}$
OUTPUT DETECTOR						
*Peak off-state voltage (4N39)	V_{DM}	200			V	$R_{GK} = 10 \text{ k}\Omega, T_A = 100^\circ\text{C}$
(4N40)	V_{DM}	400			V	$R_{GK} = 10 \text{ k}\Omega, T_A = 100^\circ\text{C}$
*Peak reverse voltage (4N39)	V_{RM}	200			V	$T_A = 100^\circ\text{C}$
(4N40)	V_{RM}	400			V	$T_A = 100^\circ\text{C}$
*On-state voltage	V_T			1.3	V	$I_T = 300 \text{ mA}$
*Off-state current (4N39)	I_{DM}			50	μA	$V_{DM} = 200 \text{ V}, T_A = 100^\circ\text{C}, I_F = 0, R_{GK} = 10 \text{ K}\Omega$
(4N40)	I_{DM}			150	μA	$V_{DM} = 400 \text{ V}, T_A = 100^\circ\text{C}, I_F = 0, R_{GK} = 10 \text{ K}\Omega$
*Reverse current (4N39)	I_R			50	μA	$V_R = 200 \text{ V}, T_A = 100^\circ\text{C}, I_F = 0$
(4N40)	I_R			150	μA	$V_R = 400 \text{ V}, T_A = 100^\circ\text{C}, I_F = 0$
*Holding current	I_R			1.0	mA	$V_{F_A} = 50 \text{ V}, R_{GK} = 27 \text{ k}\Omega$

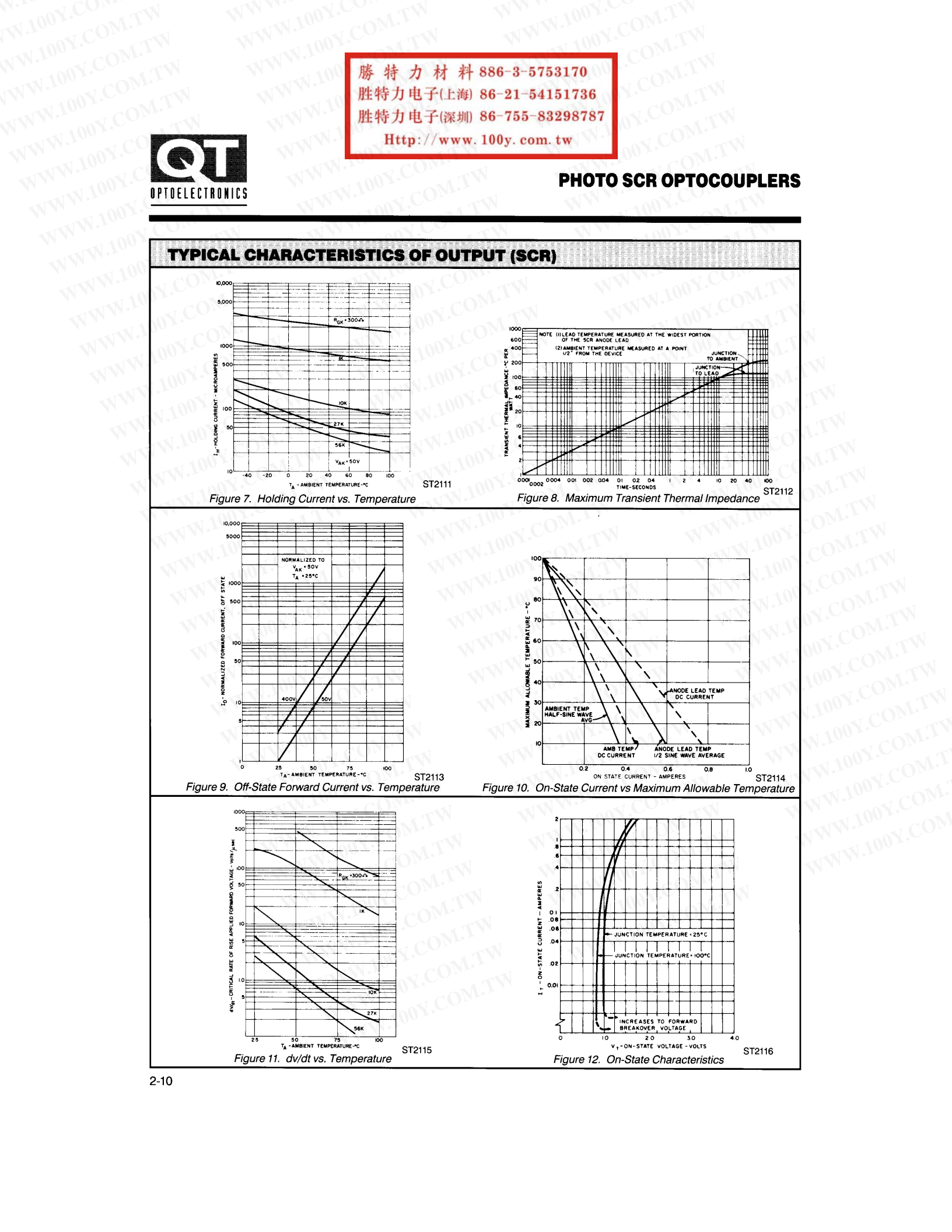
TRANSFER CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
*Input current to trigger (4N39, 4N40)	I_{FT}			30	mA	$V_{AK} = 50 \text{ V}, R_{GK} = 10 \text{ k}\Omega$
(4N39, 4N40)	I_{FT}			14	mA	$V_{AK} = 100 \text{ V}, R_{GK} = 27 \text{ k}\Omega$
*Turn-on time	t_{on}			50	μs	$V_{AK} = 50 \text{ V}, I_F = 30 \text{ mA}, R_{GK} = 10 \text{ k}\Omega, R_L = 200 \Omega$
Package capacitance (input to output)				2	pF	Input to output voltage=0 $f = 1 \text{ MHz}$
Coupled dv/dt, input to output (figure 13)		500			V/ μs	

ISOLATION CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Surge isolation voltage	V_{ISO}	7500			V	1 Minute
Isolation voltage	V_{ISO}	5300			V	1 Minute
*Isolation resistance	R_{ISO}	10^{11}			ohms	$V_{IO} = 500 \text{ VDC}$

*Indicates JEDEC Registered Data

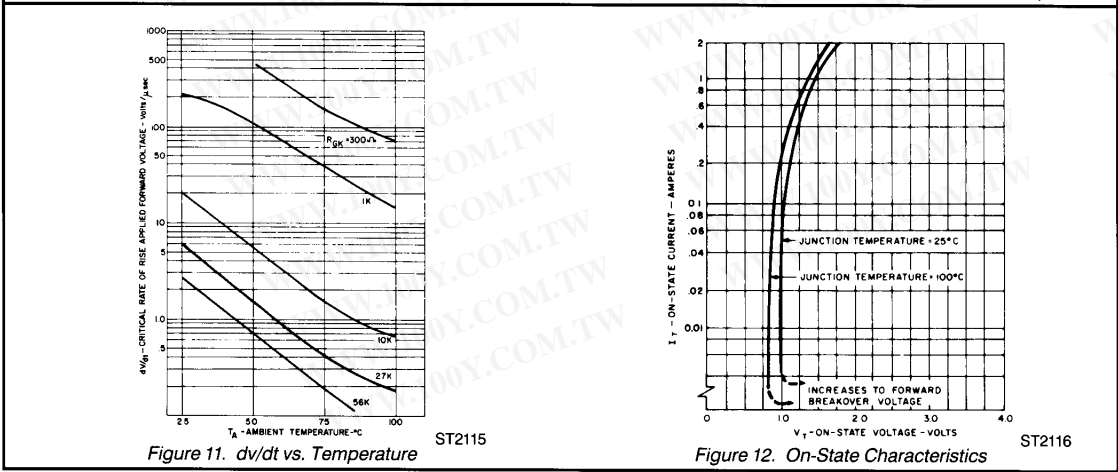
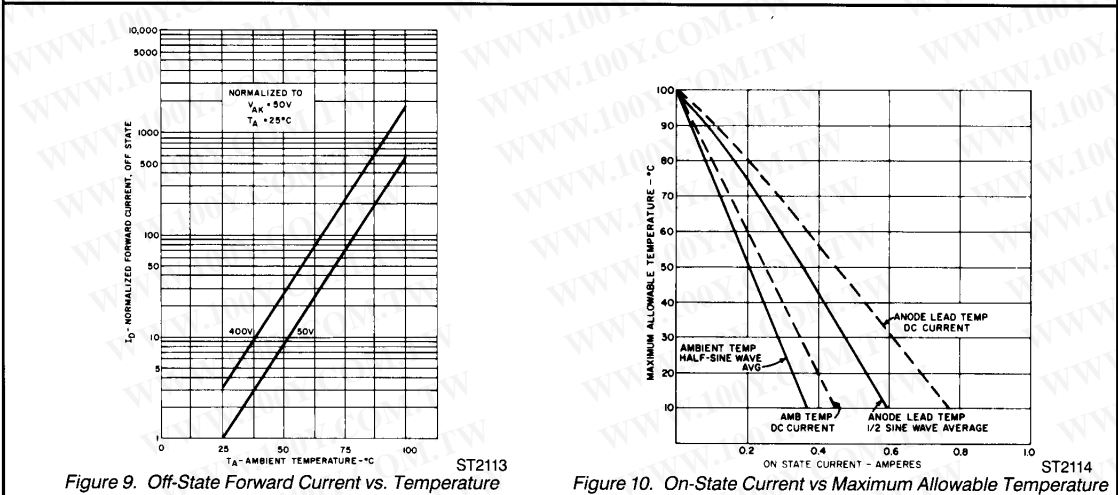
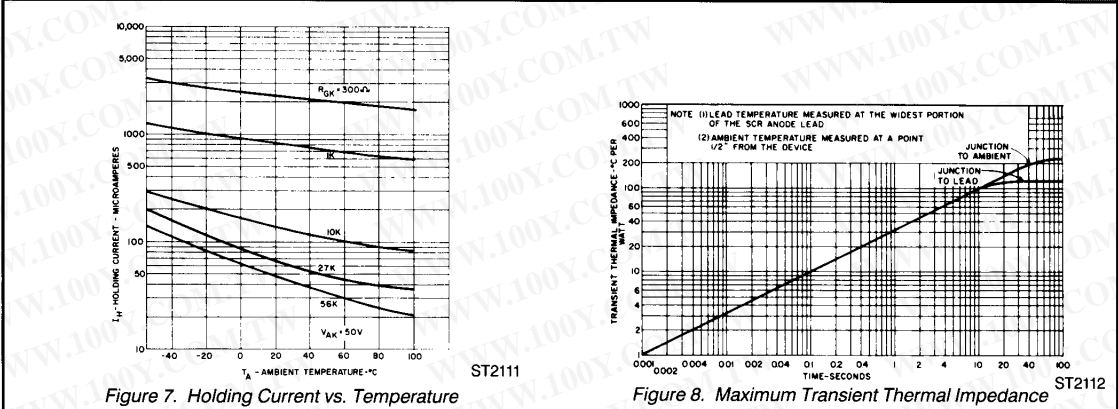


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TYPICAL CHARACTERISTICS OF OUTPUT (SCR)



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DUAL SPLIT-DARLINGTON OPTOCOUPLEDERS

TYPICAL ELECTRO-OPTICAL CHARACTERISTICS

($T_A = 0^\circ\text{C}$ to 70°C Unless Otherwise Specified)

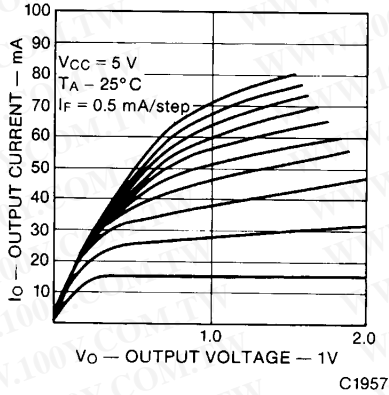


Fig. 1. DC Transfer Characteristics

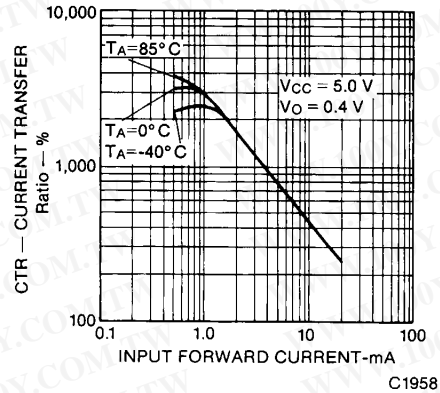


Fig. 2. Current Transfer Ratio vs. Input Forward Current

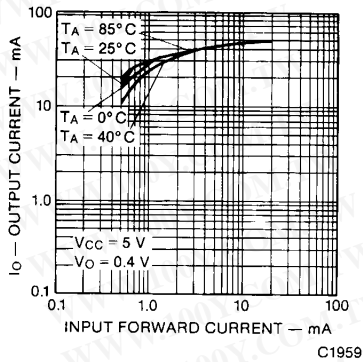


Fig. 3. Output Current vs. Input Forward Current

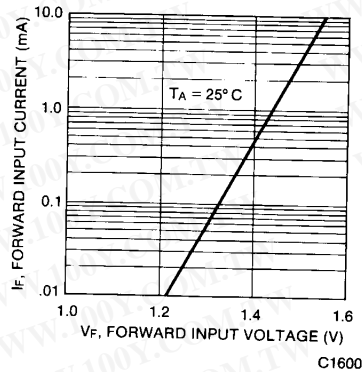


Fig. 4. Forward Input Current vs. Forward Input Voltage

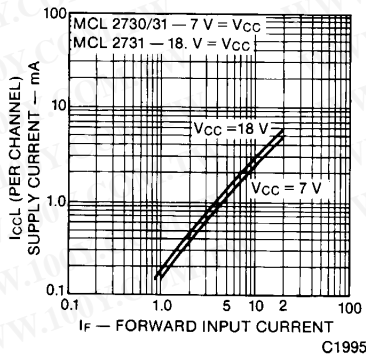


Fig. 5. Supply Current Per Channel vs. Input Forward Current

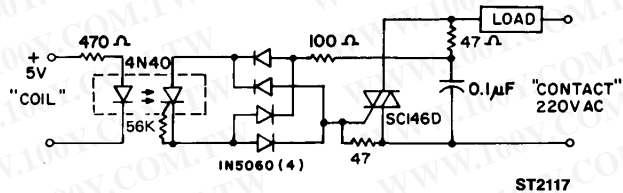


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TYPICAL APPLICATIONS

10A, T^L COMPATIBLE, SOLID STATE RELAY

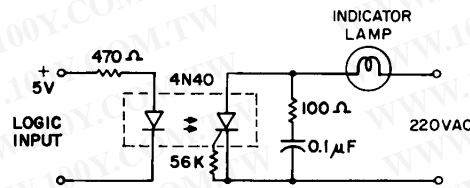
Use of the 4N40 for high sensitivity, 5300V isolation capability, provides this highly reliable solid state relay design. This design is compatible with 74, 74S and 74H series T^L logic systems inputs and 220V AC loads up to 10A.



ST2117

25W, LOGIC INDICATOR LAMP DRIVER

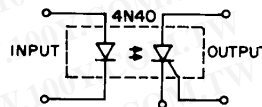
The high surge capability and non-reactive input characteristics of the 4N40 allow it to directly couple, without buffers, T^L and DTL logic to indicator alarm devices, without danger of introducing noise and logic glitches.



ST2118

400V SYMMETRICAL TRANSISTOR COUPLER

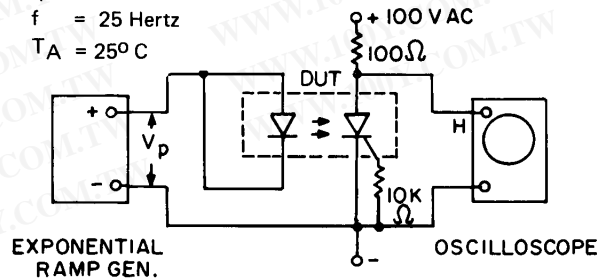
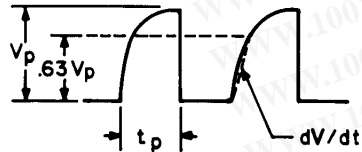
Use of the high voltage PNP portion of the 4N40 provides a 400V transistor capable of conducting positive and negative signals with current transfer ratios of over 1%. This function is useful in remote instrumentation, high voltage power supplies and test equipment. Care should be taken not to exceed the 400 mW power dissipation rating when used at high voltages.



ST2119

FIGURE 13
COUPLED dv/dt - TEST CIRCUIT

$V_p = 800$ Volts
 $t_p = .010$ Seconds
 $f = 25$ Hertz
 $T_A = 25^\circ$ C



ST2120